NSN 5961-01-376-5416

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-376-5416

Inclosure Material:
Plastic or ceramic or glass
Overall Length:
Between 0.140 inches and 0.250 inches
Terminal Length:
Between 1.000 inches and 1.500 inches
Overall Diameter:
Between 0.065 inches and 0.150 inches
Mounting Method:
Terminal
Features Provided:
Burn in
Cubic Measure:
0.017 cubic inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
800.0 working peak reverse voltage
Current Rating Per Characteristic:
1.00 amperes forward current, average absolute and 15.00 amperes forward current, average preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
81349-mil-s-19500/359 government specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0